

## LME49740 Quad High Performance, High Fidelity Audio Operational Amplifier

Check for Samples: [LME49740](#), [LME49740MABD](#), [LME49740NABD](#)

### FEATURES

- Easily drives 600Ω loads
- Optimized for superior audio signal fidelity
- Output short circuit protection
- PSRR and CMRR exceed 120dB (typ)
- SOIC and DIP packages

### APPLICATIONS

- Ultra high quality audio amplification
- High fidelity preamplifiers
- High fidelity multimedia
- State of the art phono pre amps
- High performance professional audio
- High fidelity equalization and crossover networks
- High performance line drivers
- High performance line receivers
- High fidelity active filters

### DESCRIPTION

The LME49740 is part of the ultra-low distortion, low noise, high slew rate operational amplifier series optimized and fully specified for high performance, high fidelity applications. Combining advanced leading-edge process technology with state-of-the-art circuit design, the LME49740 audio operational amplifiers deliver superior audio signal amplification for outstanding audio performance. The LME49740 combines extremely low voltage noise density (2.7nV/√Hz) with vanishingly low THD+N (0.00003%) to easily satisfy the most demanding audio applications. To ensure that the most challenging loads are driven without compromise, the LME49740 has a high slew rate of ±20V/μs and an output current capability of ±26mA. Further, dynamic range is maximized by an output stage that drives 2kΩ loads to within 1V of either power supply voltage and to within 1.4V when driving 600Ω loads.

The LME49740's outstanding CMRR(120dB), PSRR(120dB), and  $V_{OS}$ (0.1mV) give the amplifier excellent operational amplifier DC performance.

The LME49740 has a wide supply range of ±2.5V to ±17V. Over this supply range the LME49740's input circuitry maintains excellent common-mode and power supply rejection, as well as maintaining its low input bias current. The LME49740 is unity gain stable. The Audio Operational Amplifier achieves outstanding AC performance while driving complex loads with values as high as 100pF.

The LME49740 is available in 14-lead narrow body SOIC and 14-lead plastic DIP. Demonstration boards are available for each package.

**Table 1. Key Specifications**

	VALUE	UNIT
Power Supply Voltage Range	±2.5V to ±17V	
THD+N ( $A_V = 1$ , $V_{OUT} = 3V_{RMS}$ , $f_{IN} = 1kHz$ )		
$R_L = 2k\Omega$	0.00003	% (typ)
$R_L = 600\Omega$	0.00003	% (typ)
Input Noise Density	2.7	nV/√Hz (typ)
Slew Rate	±20	V/μs (typ)
Gain Bandwidth Product	55	MHz (typ)
Open Loop Gain ( $R_L = 600\Omega$ )	140	dB (typ)
Input Bias Current	10	nA (typ)
Input Offset Voltage	0.1	mV (typ)



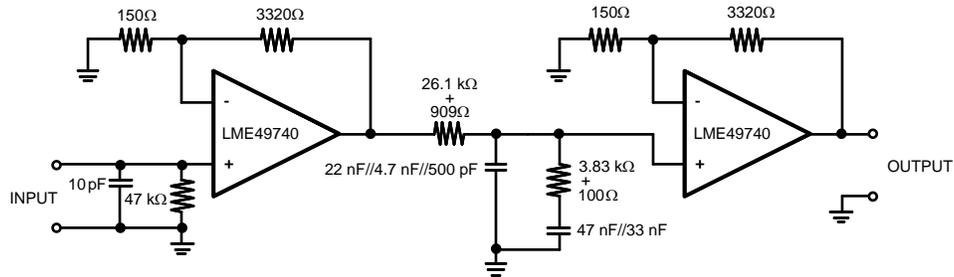
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**Table 1. Key Specifications (continued)**

	VALUE	UNIT
DC Gain Linearity Error	0.000009	%

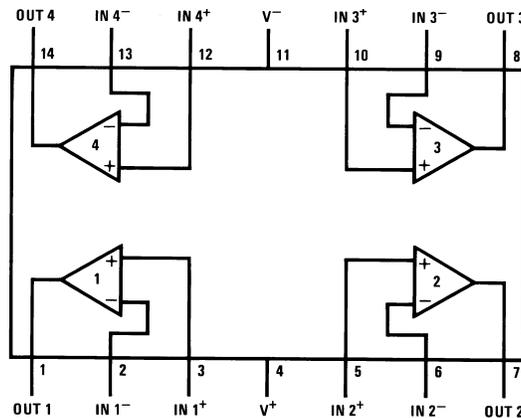
**Typical Application**



Note: 1% metal film resistors, 5% polypropylene capacitors

**Figure 1. Passively Equalized RIAA Phono Preamplifier**

**Connection Diagram**



**Figure 2. Diagram**



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

**Absolute Maximum Ratings** <sup>(1) (2)</sup>

Power Supply Voltage ( $V_S = V^+ - V^-$ )	36V
Storage Temperature	-65°C to 150°C
Input Voltage	(V-) - 0.7V to (V+) + 0.7V
Output Short Circuit <sup>(3)</sup>	Continuous
Power Dissipation	Internally Limited
ESD Susceptibility <sup>(4)</sup>	2000V
ESD Susceptibility <sup>(5)</sup>	200V
Junction Temperature	150°C
Thermal Resistance	
$\theta_{JA}$ (MA)	107°C/W
$\theta_{JA}$ (NA)	74°C/W
Temperature Range	
$T_{MIN} \leq T_A \leq T_{MAX}$	-40°C $\leq$ $T_A$ $\leq$ 85°C
Supply Voltage Range	$\pm 2.5V \leq V_S \leq \pm 17V$

- (1) *Absolute Maximum Ratings* indicate limits beyond which damage to the device may occur.
- (2) Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.
- (3) Amplifier output connected to GND, any number of amplifiers within a package.
- (4) Human body model, 100pF discharged through a 1.5k $\Omega$  resistor.
- (5) Machine Model ESD test is covered by specification EIAJ IC-121-1981. A 200pF cap is charged to the specified voltage and then discharged directly into the IC with no external series resistor (resistance of discharge path must be under 50 $\Omega$ ).

**Electrical Characteristics**<sup>(1) (2)</sup>

The following specifications apply for  $V_S = \pm 15V$ ,  $R_L = 2k\Omega$ ,  $f_{IN} = 1kHz$ , and  $T_A = 25C$ , unless otherwise specified.

Symbol	Parameter	Conditions	LME49740		Units (Limits)
			Typical	Limit	
			(3)	(4) (5)	
THD+N	Total Harmonic Distortion + Noise	$A_V = 1, V_{OUT} = 3V_{RMS}$ $R_L = 2k\Omega$ $R_L = 600\Omega$	0.00003 0.00003	0.00009	% (max) % (max)
IMD	Intermodulation Distortion	$A_V = 1, V_{OUT} = 3V_{RMS}$ Two-tone, 60Hz & 7kHz 4:1	0.00005		% (max)
GBWP	Gain Bandwidth Product		55	45	MHz (min)
SR	Slew Rate		$\pm 20$	$\pm 15$	V/ $\mu s$ (min)
FPBW	Full Power Bandwidth	$V_{OUT} = 1V_{P-P}, -3dB$ referenced to output magnitude at $f = 1kHz$	10		MHz
$t_s$	Settling time	$A_V = 1, 10V$ step, $C_L = 100pF$ 0.1% error range	1.2		$\mu s$
$e_n$	Equivalent Input Noise Voltage	$f_{BW} = 20Hz$ to $20kHz$	0.34	0.65	$\mu V_{RMS}$
	Equivalent Input Noise Density	$f = 1kHz$ $f = 10Hz$	2.7 6.4	4.7	$nV/\sqrt{Hz}$ $nV/\sqrt{Hz}$
$i_n$	Current Noise Density	$f = 1kHz$ $f = 10Hz$	1.6 3.1		$pA/\sqrt{Hz}$ $pA/\sqrt{Hz}$
$V_{OS}$	Offset Voltage		$\pm 0.1$	$\pm 0.7$	mV (max)
$\Delta V_{OS}/\Delta Temp$	Average Input Offset Voltage Drift vs Temperature	$40^\circ C \leq T_A \leq 85^\circ C$	0.2		$\mu V/^\circ C$
PSRR	Average Input Offset Voltage Shift vs Power Supply Voltage	$\Delta V_S = 20V^{(6)}$	120	110	dB (min)
ISO <sub>CH-CH</sub>	Channel-to-Channel Isolation	$f_{IN} = 1kHz$ $f_{IN} = 20kHz$	118 112		dB dB
$I_B$	Input Bias Current	$V_{CM} = 0V$	10	72	nA (max)
$\Delta I_{OS}/\Delta Temp$	Input Bias Current Drift vs Temperature	$-40^\circ C \leq T_A \leq 85^\circ C$	0.1		nA/ $^\circ C$
$I_{OS}$	Input Offset Current	$V_{CM} = 0V$	11	65	nA (max)
$V_{IN-CM}$	Common-Mode Input Voltage Range		+14.1 -13.9	(V+)-2.0 (V-)+2.0	V (min) V (min)
CMRR	Common-Mode Rejection	$-10V < V_{CM} < 10V$	120	110	dB (min)
$Z_{IN}$	Differential Input Impedance		30		k $\Omega$
	Common Mode Input Impedance	$-10V < V_{CM} < 10V$	1000		M $\Omega$
$A_{VOL}$	Open Loop Voltage Gain	$-10V < V_{OUT} < 10V, R_L = 600\Omega$	140		dB (min)
		$-10V < V_{OUT} < 10V, R_L = 2k\Omega$	140		dB (min)
		$-10V < V_{OUT} < 10V, R_L = 10k\Omega$	140	125	dB (min)
$V_{OUTMAX}$	Maximum Output Voltage Swing	$R_L = 600\Omega$	$\pm 13.6$	$\pm 12.5$	V (min)
		$R_L = 2k\Omega$	$\pm 14.0$		V (min)
		$R_L = 10k\Omega$	$\pm 14.1$		V (min)
$I_{OUT}$	Output Current	$R_L = 600\Omega, V_S = \pm 17V$	$\pm 26$	$\pm 23$	mA (min)
$I_{OUT-CC}$	Short Circuit Current		+30 -38		mA mA

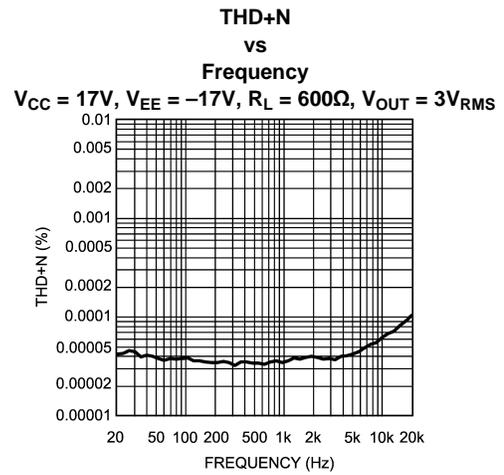
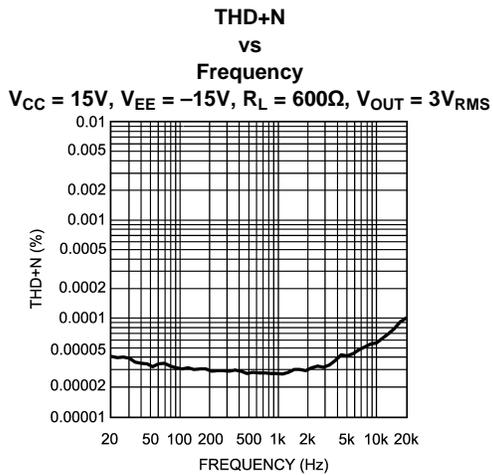
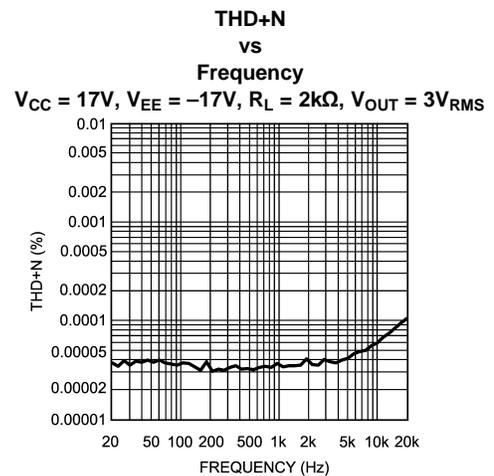
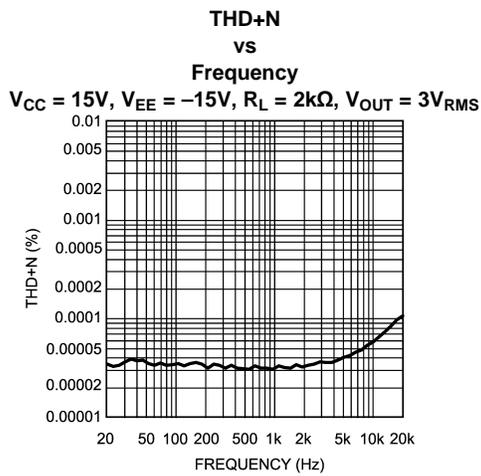
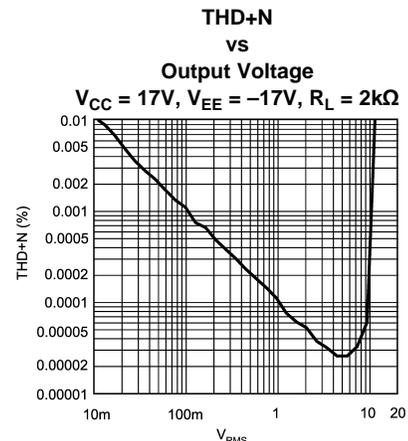
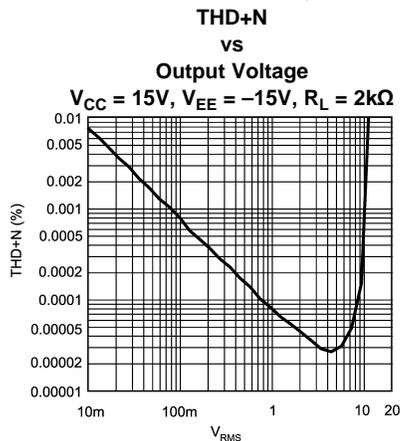
- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur.
- (2) Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.
- (3) Typical specifications are specified at +25°C and represent the most likely parametric norm.
- (4) Tested limits are guaranteed to National's AOQL (Average Outgoing Quality Level).
- (5) Datasheet min/max specification limits are guaranteed by design, test, or statistical analysis.
- (6) PSRR is measured as follows:  $V_{OS}$  is measured at two supply voltages,  $\pm 5V$  and  $\pm 15V$ .  $PSRR = |20\log(\Delta V_{OS}/\Delta V_S)|$ .

**Electrical Characteristics<sup>(1) (2)</sup> (continued)**

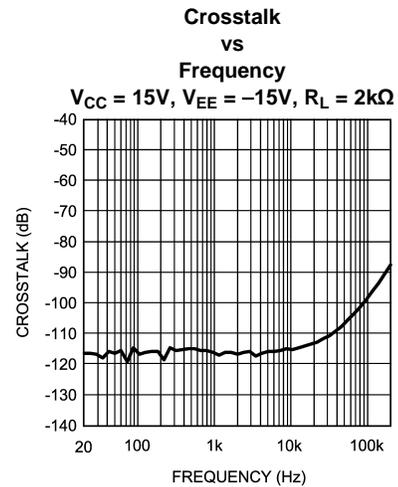
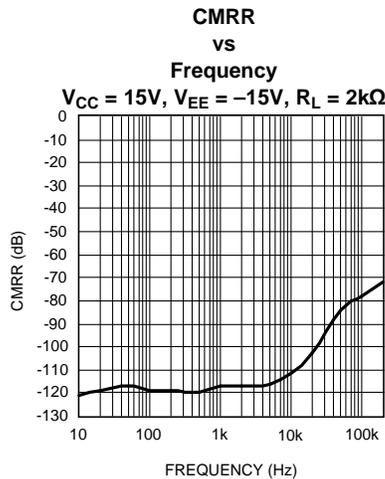
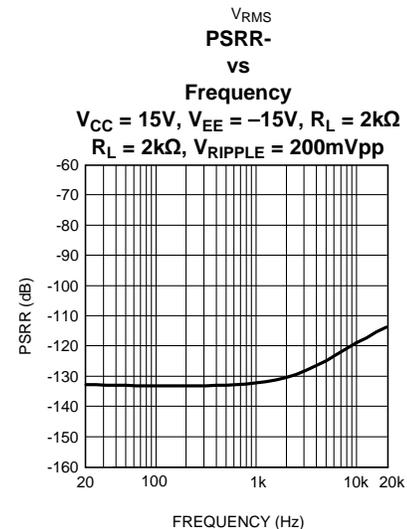
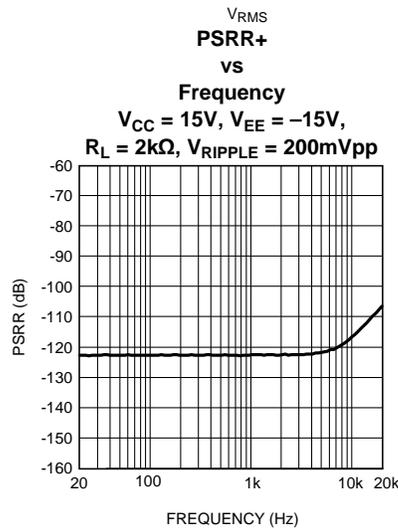
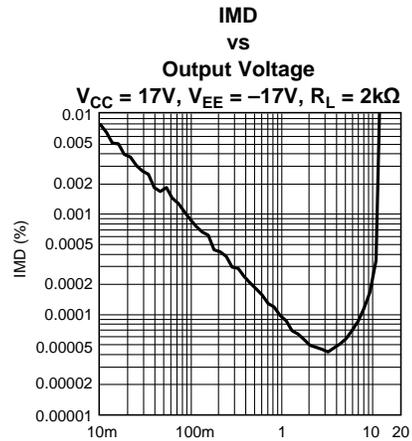
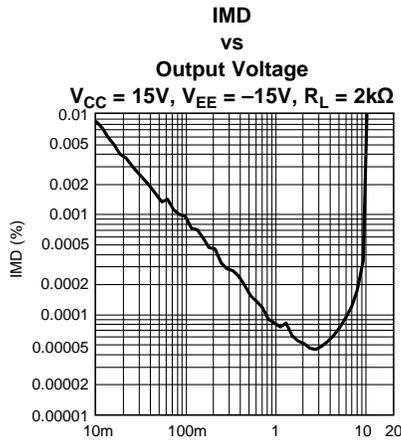
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Symbol	Parameter	Conditions	LME49740		Units (Limits)
			Typical	Limit	
			(3)	(4) (5)	
$R_{OUT}$	Output Impedance	$f_{IN} = 10kHz$ Closed-Loop Open-Loop	0.01 13		$\Omega$ $\Omega$
$C_{LOAD}$	Capacitive Load Drive Overshoot	100pF	16		%
$I_S$	Total Quiescent Current	$I_{OUT} = 0mA$	18.5	20	mA (max)

### Typical Performance Characteristics

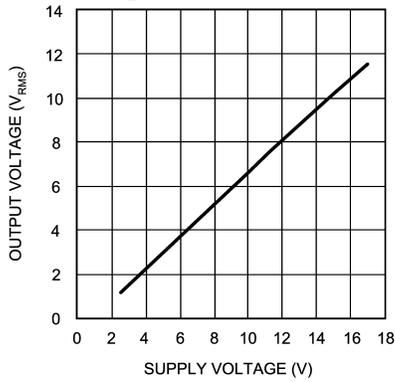


**Typical Performance Characteristics (continued)**

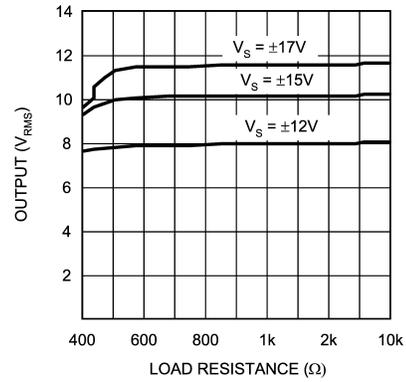


**Typical Performance Characteristics (continued)**

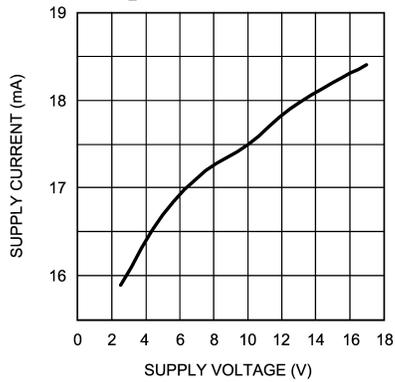
**Output Voltage vs Supply Voltage**  
 $R_L = 2k\Omega$ , THD+N = 1%



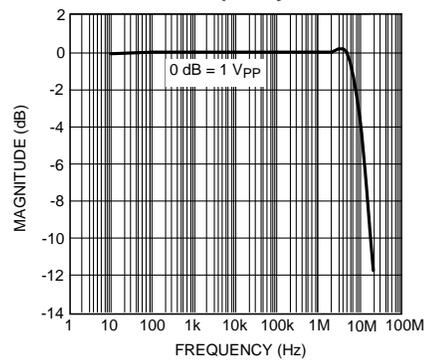
**Output Voltage vs Load Resistance**  
 THD+N = 1%



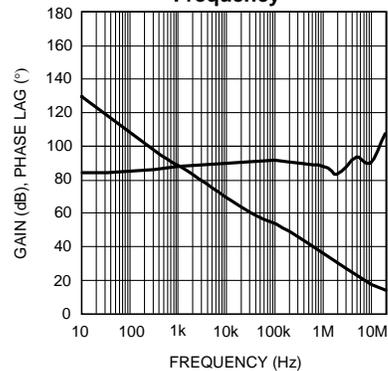
**Supply Current vs Supply Voltage**  
 $R_L = 2k\Omega$ , THD+N = 1%



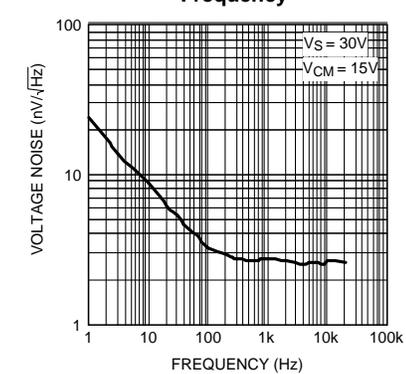
**Full Power Bandwidth vs Frequency**



**Gain Phase vs Frequency**



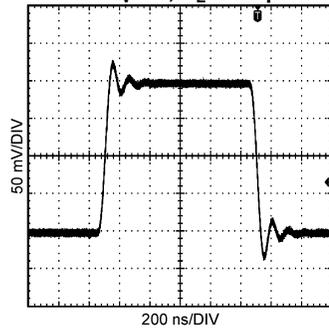
**Voltage Noise Density vs Frequency**



### Typical Performance Characteristics (continued)

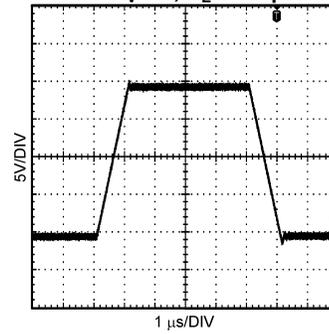
Small-Signal Transient Response

$A_V = 1, C_L = 100\text{pF}$



Large-Signal Transient Response

$A_V = 1, C_L = 100\text{pF}$



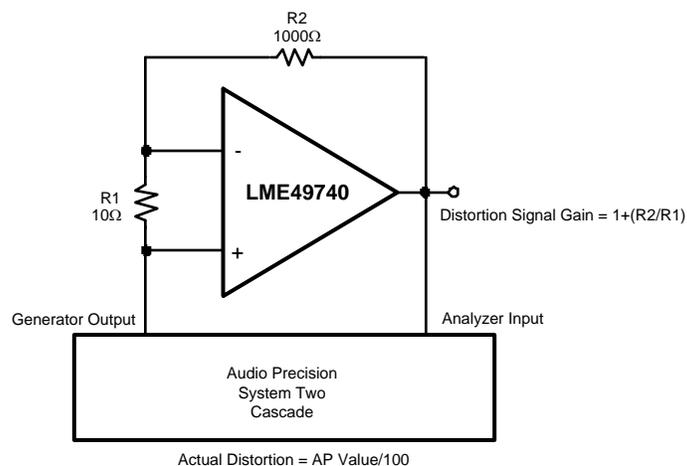
## Application Information

### DISTORTION MEASUREMENTS

The vanishingly low residual distortion produced by LME49740 is below the capabilities of all commercially available equipment. This makes distortion measurements just slightly more difficult than simply connecting a distortion meter to the amplifier's inputs and outputs. The solution, however, is quite simple: an additional resistor. Adding this resistor extends the resolution of the distortion measurement equipment.

The LME49740's low residual distortion is an input referred internal error. As shown in Figure 3, adding the 10Ω resistor connected between the amplifier's inverting and non-inverting inputs changes the amplifier's noise gain. The result is that the error signal (distortion) is amplified by a factor of 101. Although the amplifier's closed-loop gain is unaltered, the feedback available to correct distortion errors is reduced by 101, which means that measurement resolution increases by 101. To ensure minimum effects on distortion measurements, keep the value of R1 low as shown in Figure 3.

This technique is verified by duplicating the measurements with high closed loop gain and/or making the measurements at high frequencies. Doing so produces distortion components that are within the measurement equipment's capabilities. This datasheet's THD+N and IMD values were generated using the above described circuit connected to an Audio Precision System Two Cascade.



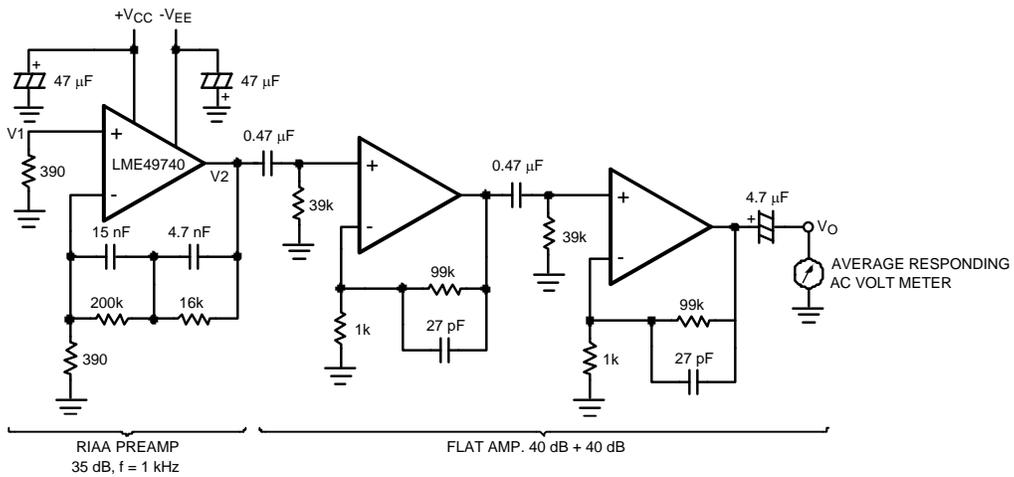
**Figure 3. THD+N and IMD Distortion Test Circuit**

### Application Hints

The LME49740 is a high speed op amp with excellent phase margin and stability. Capacitive loads up to 100pF will cause little change in the phase characteristics of the amplifiers and are therefore allowable.

Capacitive loads greater than 100pF must be isolated from the output. The most straightforward way to do this is to put a resistor in series with the output. This resistor will also prevent excess power dissipation if the output is accidentally shorted.

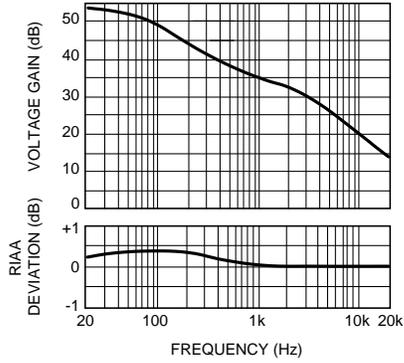
Noise Measurement Circuit



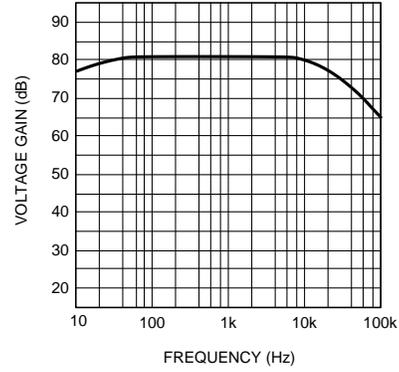
Complete shielding is required to prevent induced pick up from external sources. Always check with oscilloscope for power line noise.

**Figure 4. Total Gain: 115 dB at f = 1 kHz**  
**Input Referred Noise Voltage:  $e_n = V_o/560,000$  (V)**

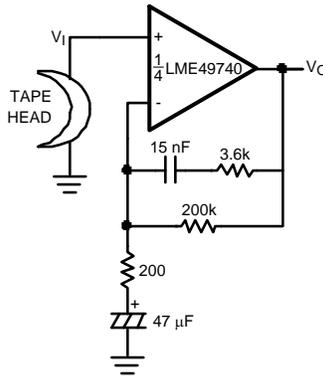
**RIAA Preamp Voltage Gain,  
RIAA Deviation  
vs  
Frequency**  
 $V_{IN} = 10\text{mV}$ ,  $A_V = 35.0\text{dB}$ ,  $f = 1\text{kHz}$



**Flat Amp Voltage Gain  
vs  
Frequency**  
 $V_O = 0\text{dB}$ ,  $A_V = 80.0\text{dB}$ ,  $f = 1\text{kHz}$

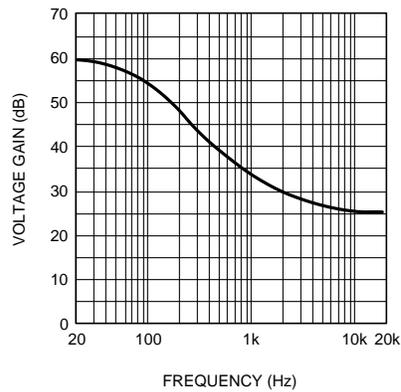


**Typical Applications**

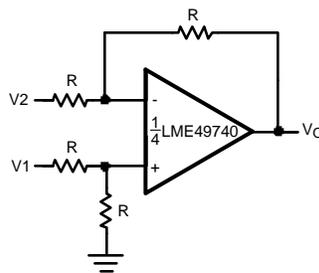


$A_V = 34.5$   
 $F = 1\text{ kHz}$   
 $E_n = 0.38\ \mu\text{V}$   
 A Weighted

**Figure 5. NAB Preamp**

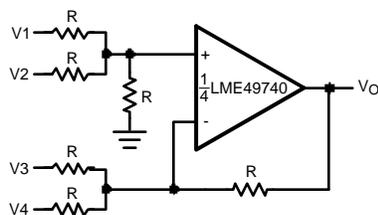


**Figure 6. NAB Preamp Voltage Gain vs Frequency**  
 $V_{IN} = 10\text{mV}$ ,  $A_V = 34.5\text{dB}$ ,  $f = 1\text{kHz}$



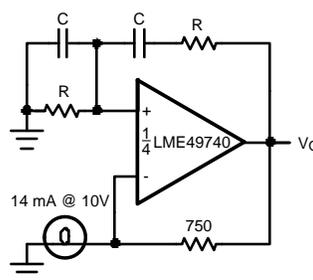
$$V_O = V_1 - V_2$$

**Figure 7. Balanced to Single Ended Converter**



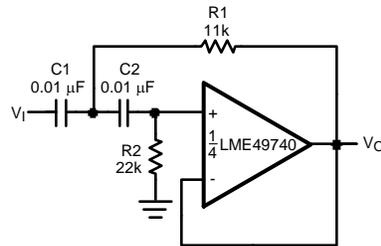
$$V_O = V_1 + V_2 - V_3 - V_4$$

Figure 8. Adder/Subtractor



$$f_o = \frac{1}{2\pi RC}$$

Figure 9. Sine Wave Oscillator



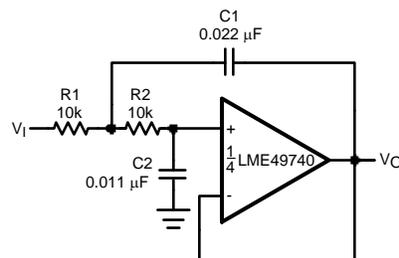
if  $C1 = C2 = C$

$$R1 = \frac{\sqrt{2}}{2\omega_0 C}$$

$$R2 = 2 \cdot R1$$

Illustration is  $f_0 = 1 \text{ kHz}$

**Figure 10. Second Order High Pass Filter (Butterworth)**



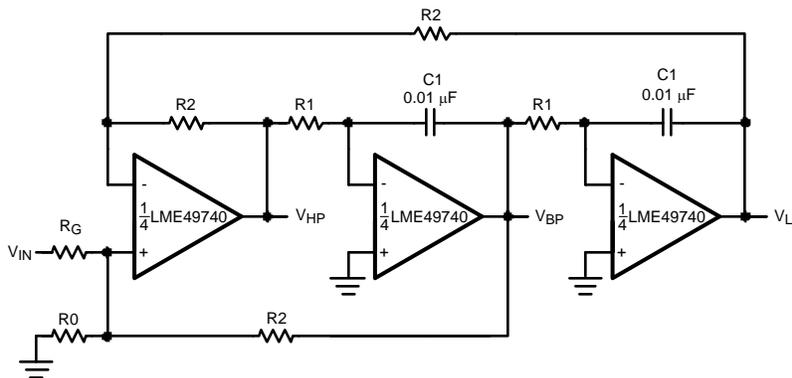
if  $R1 = R2 = R$

$$C1 = \frac{\sqrt{2}}{\omega_0 R}$$

$$C2 = \frac{C1}{2}$$

Illustration is  $f_0 = 1 \text{ kHz}$

**Figure 11. Second Order Low Pass Filter (Butterworth)**



$$f_0 = \frac{1}{2\pi C1R1}, Q = \frac{1}{2} \left( 1 + \frac{R2}{R0} + \frac{R2}{RG} \right), A_{BP} = QA_{LP} = QA_{LH} = \frac{R2}{RG}$$

Figure 12. State Variable Filter

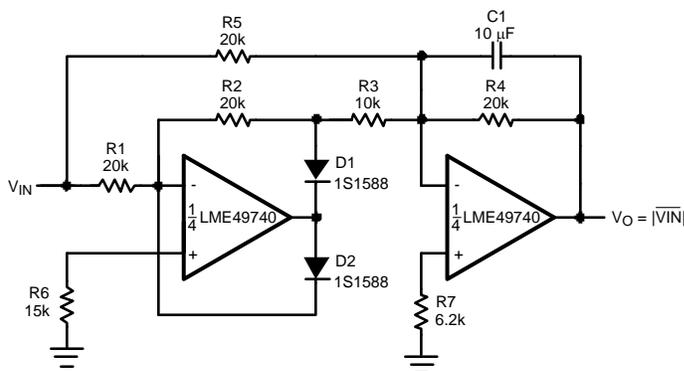


Figure 13. AC/DC Converter

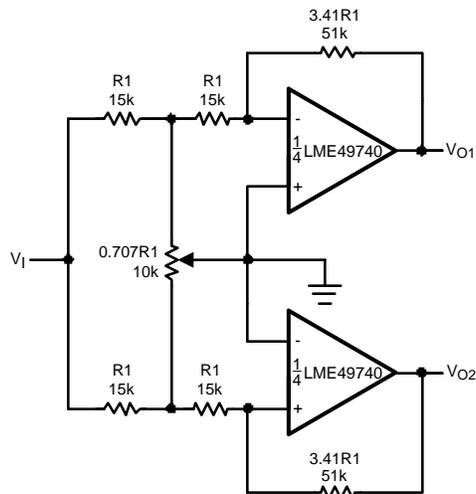


Figure 14. 2 Channel Panning Circuit (Pan Pot)

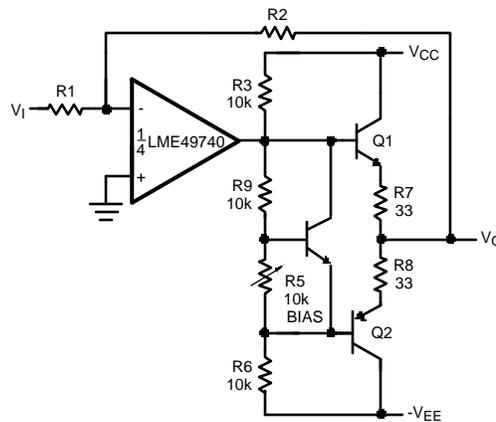
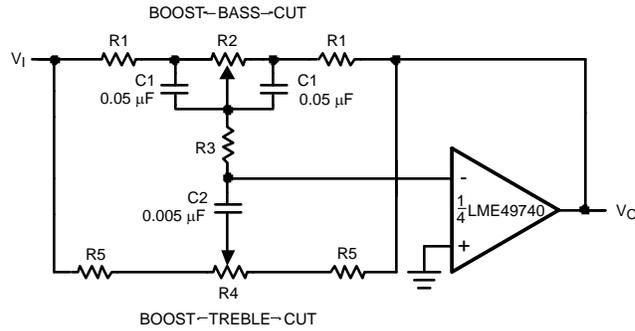


Figure 15. Line Driver



$$f_L = \frac{1}{2\pi R_2 C_1}, f_{LB} = \frac{1}{2\pi R_1 C_1}$$

$$f_H = \frac{1}{2\pi R_5 C_2}, f_{HB} = \frac{1}{2\pi (R_1 + R_5 + 2R_3) C_2}$$

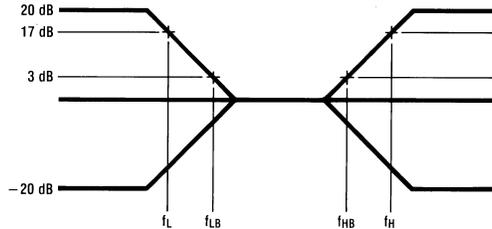
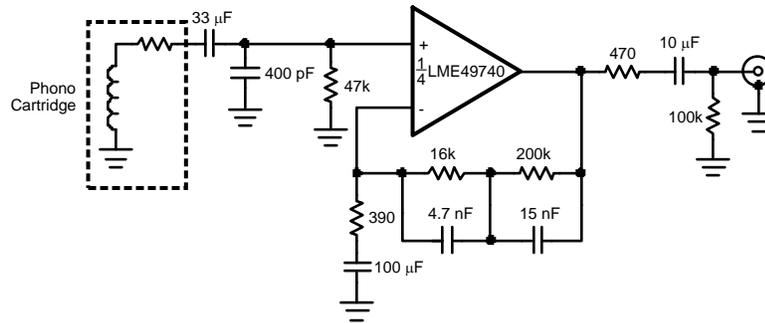
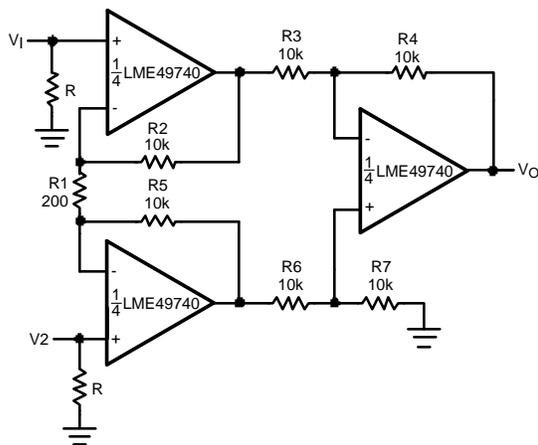


Figure 16. Tone Control



$A_v = 35 \text{ dB}$   
 $E_n = 0.33 \text{ } \mu\text{V}$   
 $S/N = 90 \text{ dB}$   
 $f = 1 \text{ kHz}$   
 A Weighted  
 A Weighted,  $V_{IN} = 10 \text{ mV}$   
 @  $f = 1 \text{ kHz}$

Figure 17. RIAA Preamp



If  $R2 = R5, R3 = R6, R4 = R7$

$$V_0 = \left(1 + \frac{2R2}{R1}\right) \frac{R4}{R3} (V2 - V1)$$

Illustration is:

$$V_0 = 101(V2 - V1)$$

Figure 18. Balanced Input Mic Amp

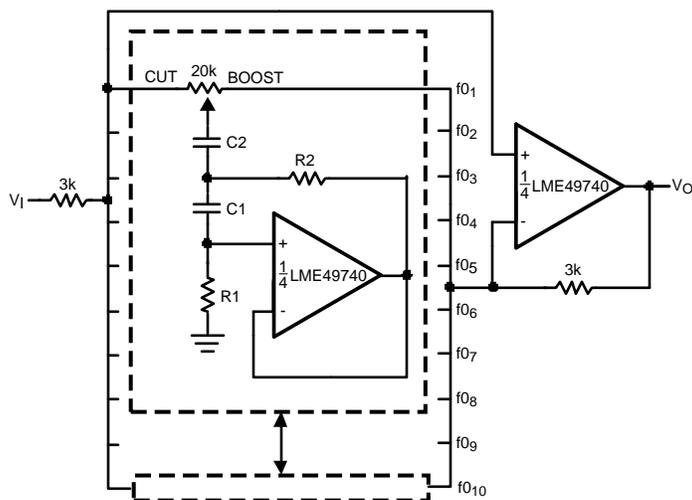


Figure 19. 10 Band Graphic Equalizer

fo (Hz)	C <sub>1</sub>	C <sub>2</sub>	R <sub>1</sub>	R <sub>2</sub>
32	0.12µF	4.7µF	75kΩ	500Ω
64	0.056µF	3.3µF	68kΩ	510Ω
125	0.033µF	1.5µF	62kΩ	510Ω
250	0.015µF	0.82µF	68kΩ	470Ω
500	8200pF	0.39µF	62kΩ	470Ω
1k	3900pF	0.22µF	68kΩ	470Ω
2k	2000pF	0.1µF	68kΩ	470Ω
4k	1100pF	0.056µF	62kΩ	470Ω
8k	510pF	0.022µF	68kΩ	510Ω
16k	330pF	0.012µF	51kΩ	510Ω

**NOTE**

At volume of change =  $\pm 12$  dB

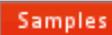
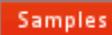
Q = 1.7

Reference: "AUDIO/RADIO HANDBOOK", National Semiconductor, 1980, Page 2–61

**Revision History**

Rev	Date	Description
1.0	02/28/07	Initial WEB release.
1.01	02/08/08	Fixed the captions on the LME4970MA package (from Dual-In-Line to Molded Package (SO)).

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
LME49740MA/NOPB	ACTIVE	SOIC	D	14	55	Green (RoHS & no Sb/Br)	SN	Level-1-260C-UNLIM	-40 to 85	LME49740 MA	
LME49740MAX/NOPB	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	SN	Level-1-260C-UNLIM	-40 to 85	LME49740 MA	
LME49740NA/NOPB	ACTIVE	PDIP	NFF	14	25	Green (RoHS & no Sb/Br)	CU SN	Level-1-NA-UNLIM	-40 to 85	LME49740NA	

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

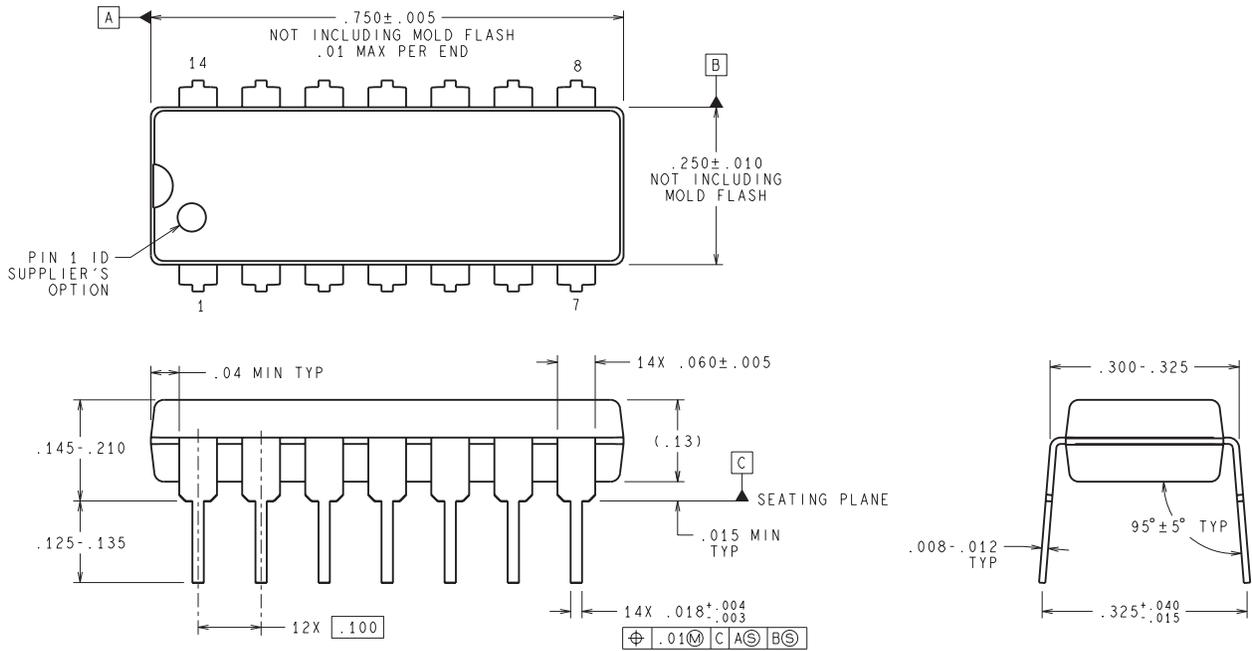
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Only one of markings shown within the brackets will appear on the physical device.

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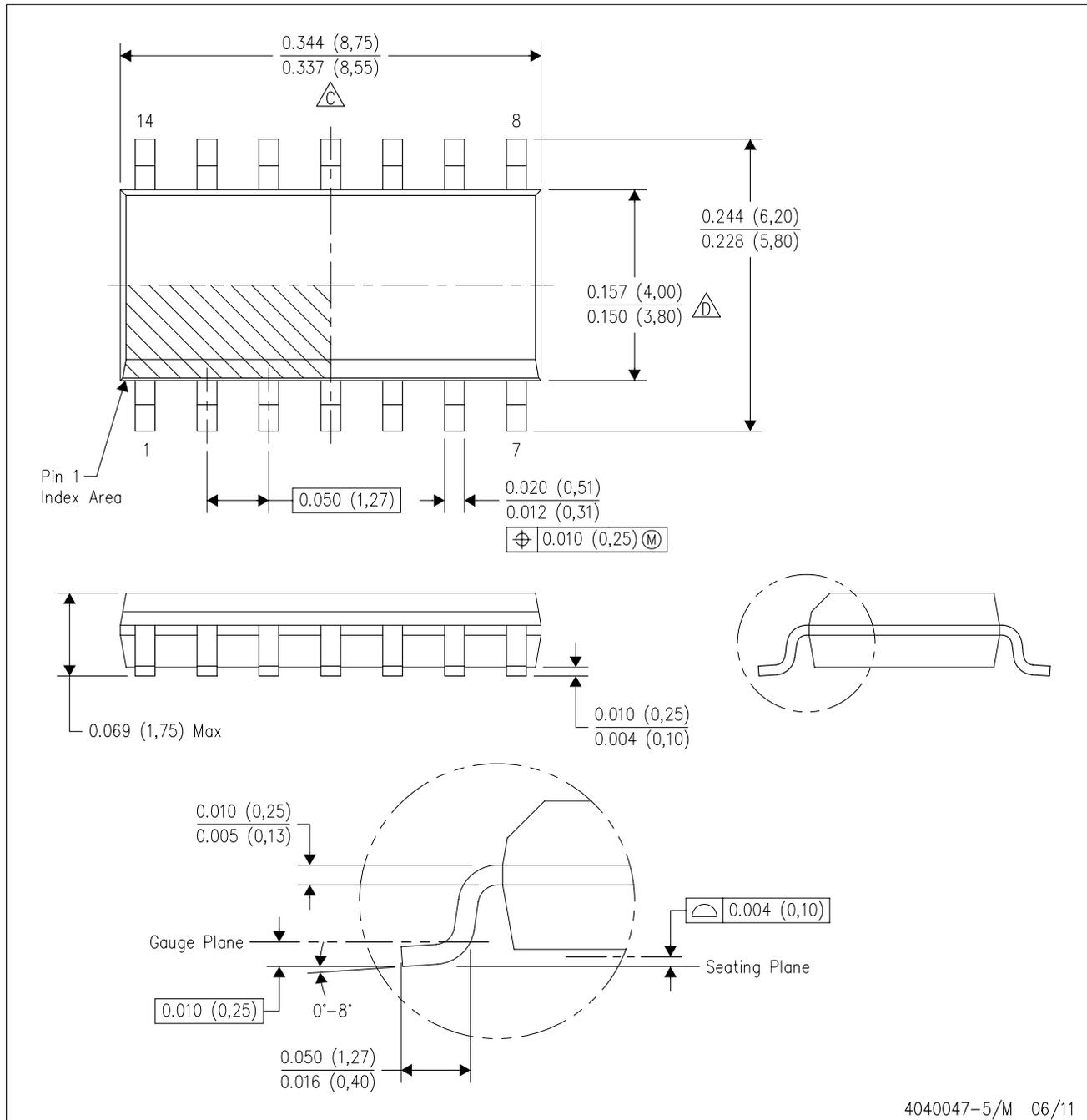


**DIMENSIONS ARE IN INCHES**  
 DIMENSIONS IN ( ) FOR REFERENCE ONLY

N14A (Rev G)

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



4040047-5/M 06/11

- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  -  Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
  -  Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
  - E. Reference JEDEC MS-012 variation AB.

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